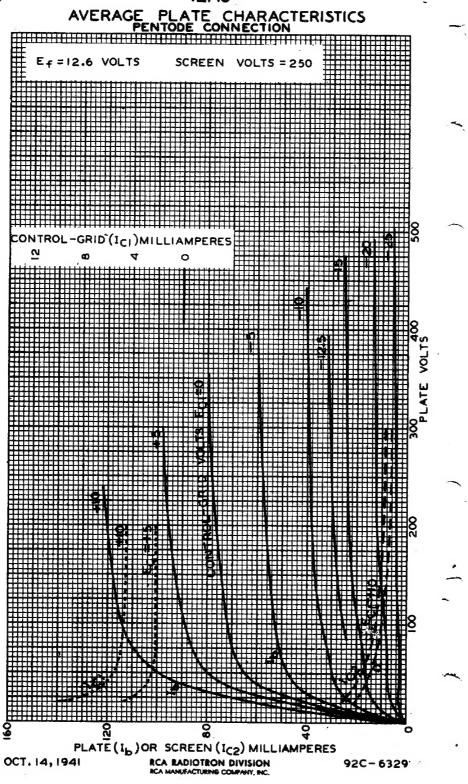




BEAM POWER AMPLIFIER

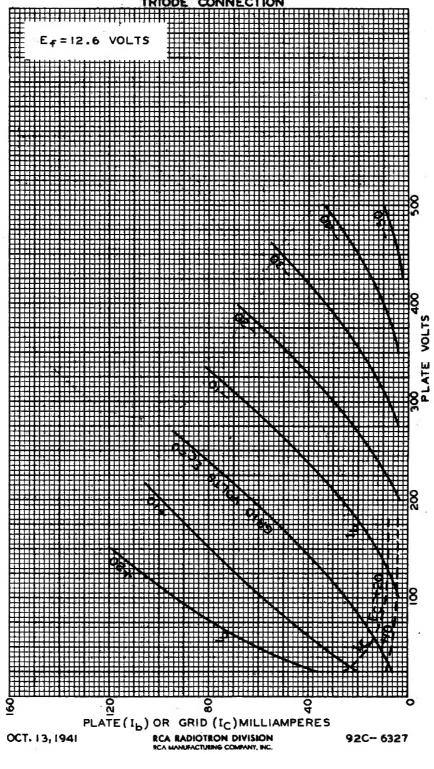
DEAM FUWER		
Heater# Coated Unipoter	ntial Cathode	
Voltage 12.		s
Current 0.1	5 amp.	_
Direct Interelectrode Capacitan		
Grid to Plate 0.3		
	F.F.	
Output 9.0		
Maximum Overall Length	3–1/4"	
Maximum Seated Height	2-11/16"	
Maximum Diameter	1-5/16"	
Bul b	Metal Shell, MT-	R
Base	Small Wafer Octal 7-Pi	~
Pin 1 – Sheli	Pin 5 – Grid	" "
Pin 2-Heater	Pin 7 - Heater	
Pin 3-Plate) rin / - neater	
	Pin 8 - Cathode	
Pin 4 – Screen	5	
Mounting Position (KEY)	An:	y .
BOTTOM VIE	• • • • • •	
Naximum Ratings Are L	esign-Center Values	
AMPLIF	IER	
Disas Valas		
Plate Voltage	250 max. volt	S
Screen Voltage	250 max. volt	s
Plate Dissipation	7.5 max. watt	s
Screen Dissipation	1.5 max. watt	S
Operating Conditions and Charact	eristics-Class A. Amblifier	
Plate	250 volt	٠,
Screen	250 volt	- 1
Grid *	-12.5 volt	_
Peak A-F Grid Voltage		- 1
Zero-Signal Plate Current	12.5 volt	S
	30 ma.	
MaxSignal Plate Current	32 ma.	
Zero-Signal Screen Current	3.5 approx. ma.	- !
MaxSignal Screen Current	5.5 approx. ma.	
Plate Resistance	70000 approx. ohms	
Transconductance	3000 µmho:	
Load Resistance	7500 ohms	- 1
Total Harmonic Distortion	7 %	
MaxSignal Power Output	2	_
# In circuits where the cathode is not	"""	5
GIFECTLY CONNECTED to the heater . the		
potential difference between heater		
and cathode should be kept as low as possible.	; <u>₹</u> **** !	
#	χ I	
The d-c resistance in the grid cir- cuit should not exceed 0.1 megohi		
when fixed bias is used, or 0.5 meg- ohm when cathode bias is used.	. u	
ohm when cathode bias is used.	WA MAY ER A	
With shell connected to cathode.	SM.WAFER 3 km km	-
	₹	١
		- [
4.	↓ { 	
- Indicates a change.	154 MAX	1
The second of th	, iv	- 1







AVERAGE PLATE CHARACTERISTICS
TRIODE CONNECTION



5.





